

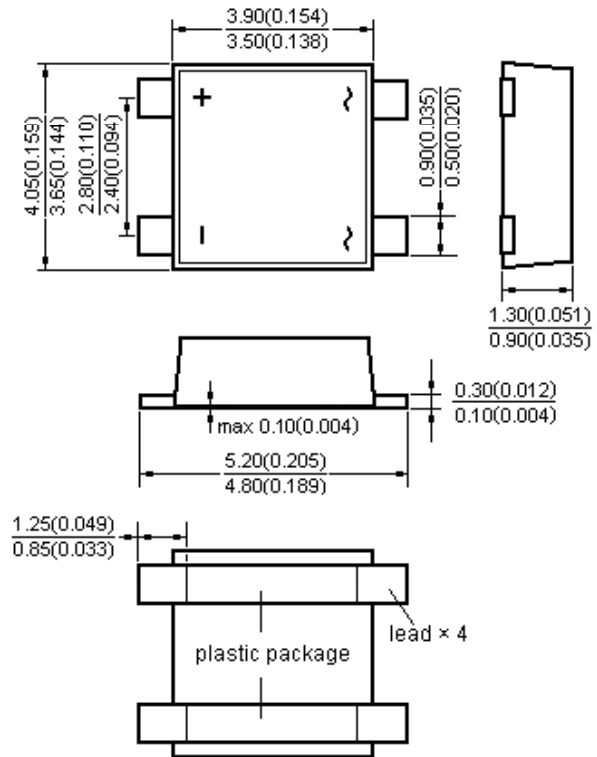


### Features

- Low profile space
- Ideal for automated placement
- Glass passivated chip junction
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High temperature soldering:  
260°C/10 seconds at terminals

### Mechanical Date

- **Case:** SOF2-4 Molded plastic over glass passivated chip
- **Terminals:** Solder plated, solderable per J-STD-002B and JESD22-B102D
- **Polarity:** Polarity symbols marked on body



### Maximum Ratings & Thermal Characteristics (T<sub>A</sub> = 25 °C unless otherwise noted)

Items	Symbol	UMB 05F	UMB 1F	UMB 2F	UMB 4F	UMB 6F	UMB 8F	UMB 10F	UNIT
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at T <sub>A</sub> =50°C -on glass-epoxy P.C.B. <sup>(1)</sup> at T <sub>A</sub> =30°C -on aluminum substrate <sup>(2)</sup>	I <sub>F(AV)</sub>	0.5 0.8						A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	20						A	
Thermal resistance from junction to ambient per leg	R <sub>θJA</sub> <sup>(1)</sup> R <sub>θJA</sub> <sup>(2)</sup>	100 80						°C/W	
Thermal resistance from junction to lead per leg <sup>(1)</sup>	R <sub>θJL</sub>	30						°C/W	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150						°C	

Note 1: On glass epoxy P.C.B. mounted on 0.05×0.05" (1.3×1.3mm) pads

Note 2: On aluminum substrate P.C.B. with an area of 0.8×0.8" (20×20mm) mounted on 0.05×0.05" (1.3×1.3mm) solder pad

### Electrical Characteristics (T<sub>A</sub> = 25 °C unless otherwise noted)

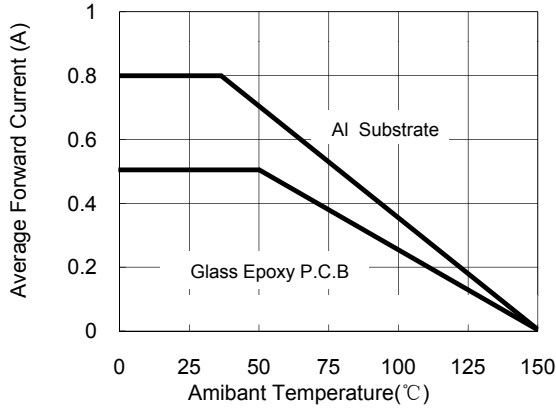
Items	Test conditions	Symbol	Min	Type	Max	UNIT
Instantaneous forward voltage per leg	I <sub>F</sub> =0.4A <sup>(3)</sup>	V <sub>F</sub>	-	0.96	1.10	V
Reverse current per leg us pulse width, 1% duty cycle.	V <sub>R</sub> =V <sub>DC</sub> T <sub>J</sub> =25°C T <sub>J</sub> =125°C	I <sub>R</sub>	-	-	5 100	μA

Note 3: Pulse test:300

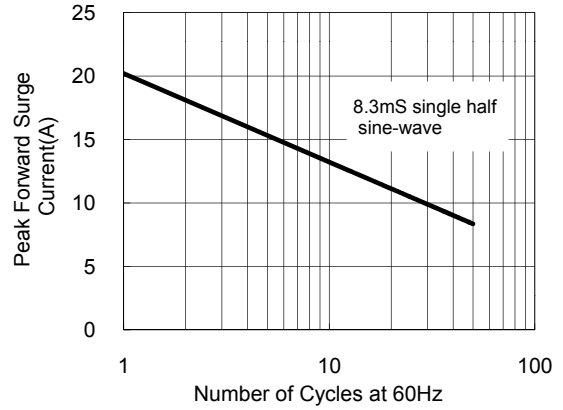


### Characteristic Curves ( $T_A=25\text{ }^\circ\text{C}$ unless otherwise noted)

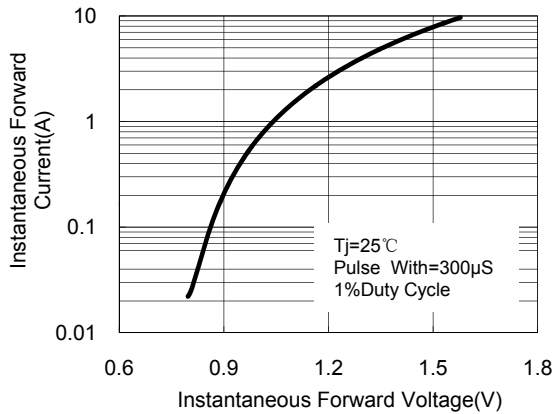
**Fig.1 Forward Current Derating Curve**



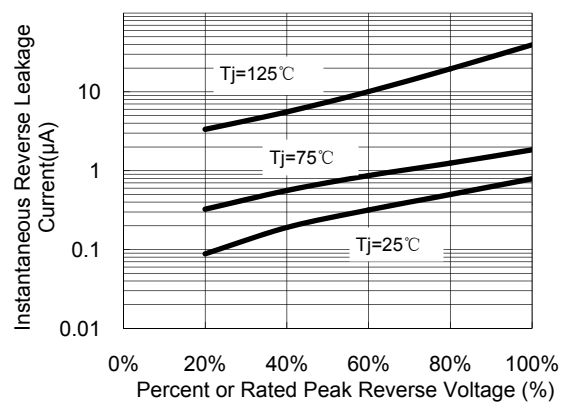
**Fig.2 Maximum Non-Repetitive Peak Forward Surge Current**



**Fig.3 Typical Instantaneous Forward Characteristics**



**Fig.4 Typical Reverse Leakage Characteristics**



### Marking

#### Annotation of Marking Code:

Device Type	Device Marking
UMB05F	B1
UMB1F	B2
UMB2F	B3
UMB4F	B4
UMB6F	B5
UMB8F	B6
UMB10F	B7